

## isc P-Channel MOSFET Transistor

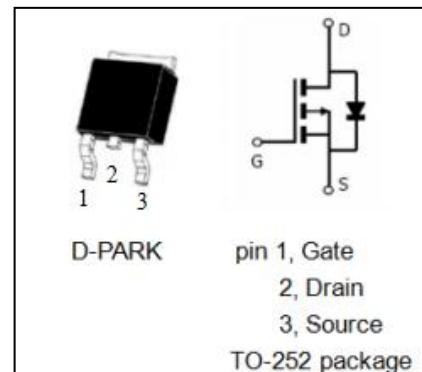
IRLR9343

## • FEATURES

- Static drain-source on-resistance:  $R_{DS(on)} \leq 105\text{m}\Omega$
- 175°C Operating Junction Temperature
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## • APPLICATIONS

- Audio amplifier applications.

• ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )

SYMBOL	PARAMETER	VALUE	UNIT
$V_{DSS}$	Drain-Source Voltage	-55	V
$V_{GS}$	Gate-Source Voltage	$\pm 20$	V
$I_D$	Drain Current-Continuous	-20	A
$I_{DM}$	Drain Current-Single Pulsed	-60	A
$P_D$	Total Dissipation @ $T_c=25^\circ\text{C}$	79	W
$T_j$ $T_{stg}$	Operating Junction And Storage Temperature	-40~175	$^\circ\text{C}$

## • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(j-c)}$	Channel-to-case thermal resistance	1.9	$^\circ\text{C}/\text{W}$

## • ELECTRICAL CHARACTERISTICS

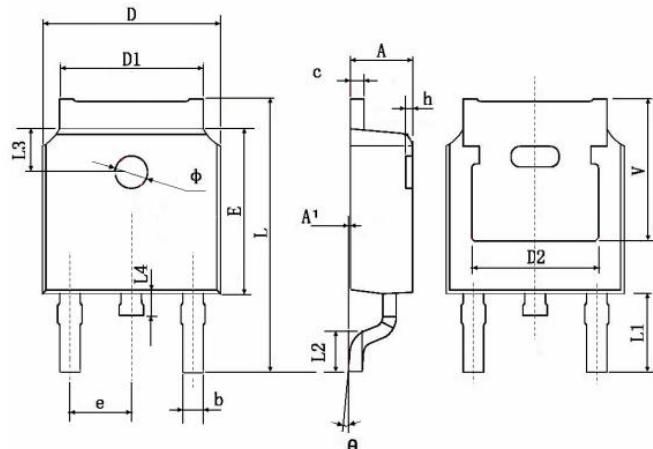
 $T_c=25^\circ\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
$BV_{DSS}$	Drain-Source Breakdown Voltage	$V_{GS}=0\text{V}; I_D = -0.25\text{mA}$	-55		V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}; I_D = -0.25\text{mA}$	-1.0		V
$R_{DS(on)}$	Drain-Source On-Resistance	$V_{GS} = -10\text{V}; I_D = -3.4\text{A}$		105	$\text{m}\Omega$
$I_{GSS}$	Gate-Source Leakage Current	$V_{GS} = \pm 20\text{V}$		$\pm 10$	$\mu\text{A}$
$I_{DSS}$	Drain-Source Leakage Current	$V_{DS} = -55\text{V}; V_{GS} = 0\text{V}$		-2	$\mu\text{A}$
$V_{SD}$	Diode forward voltage	$I_S = -14\text{A}, V_{GS} = 0\text{V}$		-1.2	V

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## TO-252 Package Outline



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.200	2.400	0.087	0.094
A1	0.000	0.127	0.000	0.005
b	0.660	0.860	0.026	0.034
c	0.460	0.580	0.018	0.023
D	6.500	6.700	0.256	0.264
D1	5.100	5.460	0.201	0.215
D2	4.830 TYP.		0.190 TYP.	
E	6.000	6.200	0.236	0.244
e	2.186	2.386	0.086	0.094
L	9.800	10.400	0.386	0.409
L1	2.900 TYP.		0.114 TYP.	
L2	1.400	1.700	0.055	0.067
L3	1.600 TYP.		0.063 TYP.	
L4	0.600	1.000	0.024	0.039
φ	1.100	1.300	0.043	0.051
θ	0°	8°	0°	8°
h	0.000	0.300	0.000	0.012
V	5.350 TYP.		0.211 TYP.	

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